DATA SHEET

74LVT652

3.3V Octal transceiver/register, non-inverting (3-State)

Product specification
Supersedes data of 1994 May 20
IC23 Data Handbook

1998 Feb 19

Philips
Semiconductors

PHILIPS

3.3V Octal transceiver/register, non-inverting (3-State)

74LVT652

FEATURES

- Independent registers for A and B buses
- Multiplexed real-time and stored data
- 3-State outputs
- Output capability: +64mA/–32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Power-up 3-State
- Power-up reset
- Latch–up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The LVT652 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device combines low static and dynamic power dissipation with high speed and high output drive.

The 74LVT652 transceiver/register consists of bus transceiver circuits with 3-State outputs, D–type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes High. Output Enable (OEAB, $\overline{OEBA}$) and Select (SAB, SBA) pins are provided for bus management.

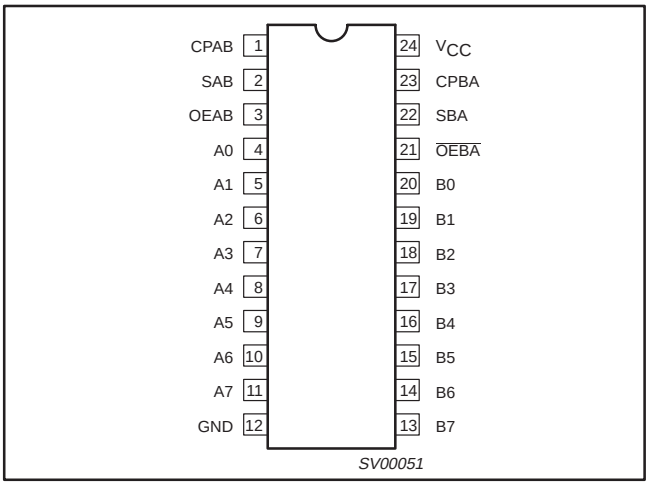
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T_{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay An to Bn or Bn to An	C_L = 50pF; V_{CC} = 3.3V	2.8 2.6	ns
C_{IN}	Input capacitance	V_I = 0V or 3V	4	pF
$C_{I/O}$	I/O capacitance	Outputs disabled; $V_{I/O}$ = 0V or 3V	10	pF
I_{CCZ}	Total supply current	Outputs disabled; V_{CC} = 3.6V	0.13	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
24-Pin Plastic SOL	–40°C to +85°C	74LVT652 D	74LVT652 D	SOT137-1
24-Pin Plastic SSOP Type II	–40°C to +85°C	74LVT652 DB	74LVT652 DB	SOT340-1
24-Pin Plastic TSSOP Type I	–40°C to +85°C	74LVT652 PW	74LVT652PW DH	SOT355-1

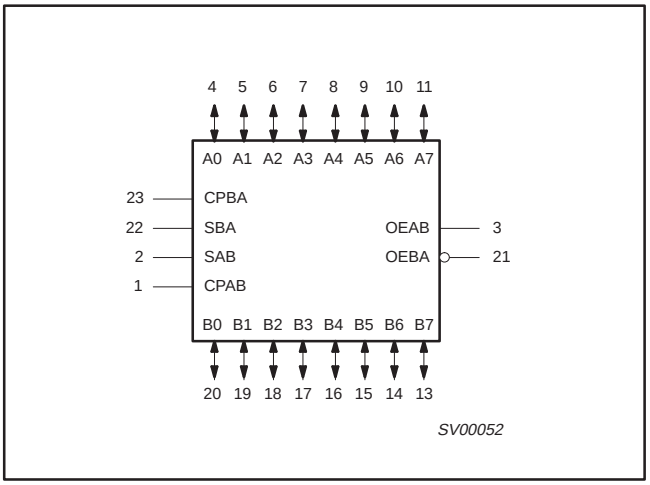
PIN CONFIGURATION



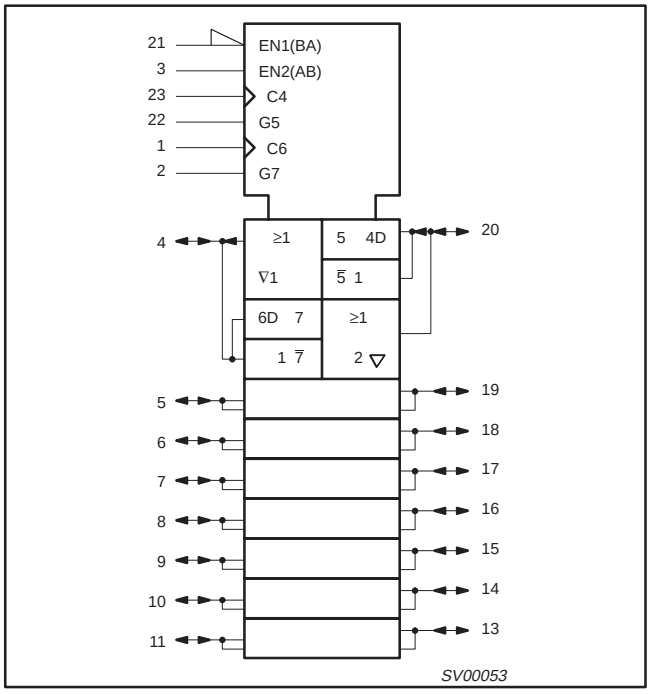
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 23	CPAB / CPBA	A to B clock input / B to A clock input
2, 22	SAB / SBA	A to B select input / B to A select input
3, 21	OEAB / $\overline{OEBA}$	A to B Output Enable input (active-High) / B to A Output Enable input (active-Low)
4, 5, 6, 7, 8, 9, 10, 11	A0 – A7	Data inputs/outputs (A side)
20, 19, 18, 17, 16, 15, 14, 13	B0 – B7	Data inputs/outputs (B side)
12	GND	Ground (0V)
24	V_{CC}	Positive supply voltage

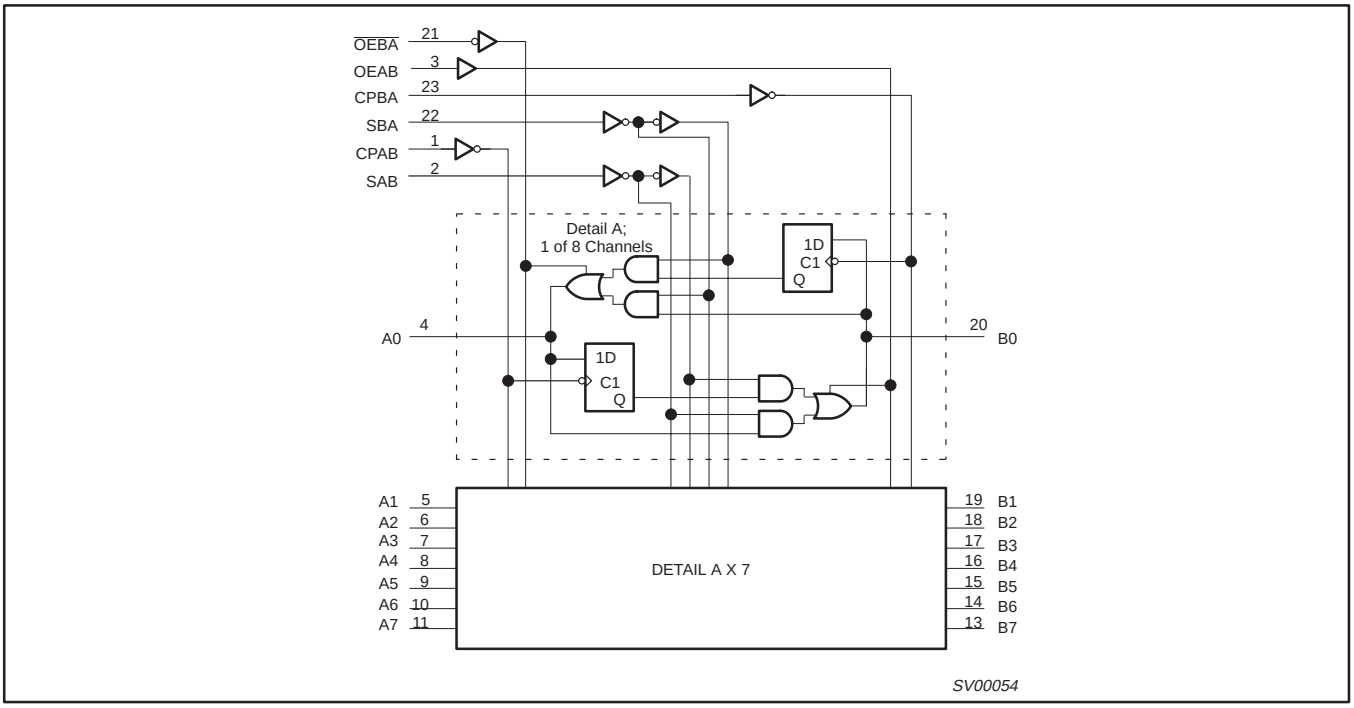
LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



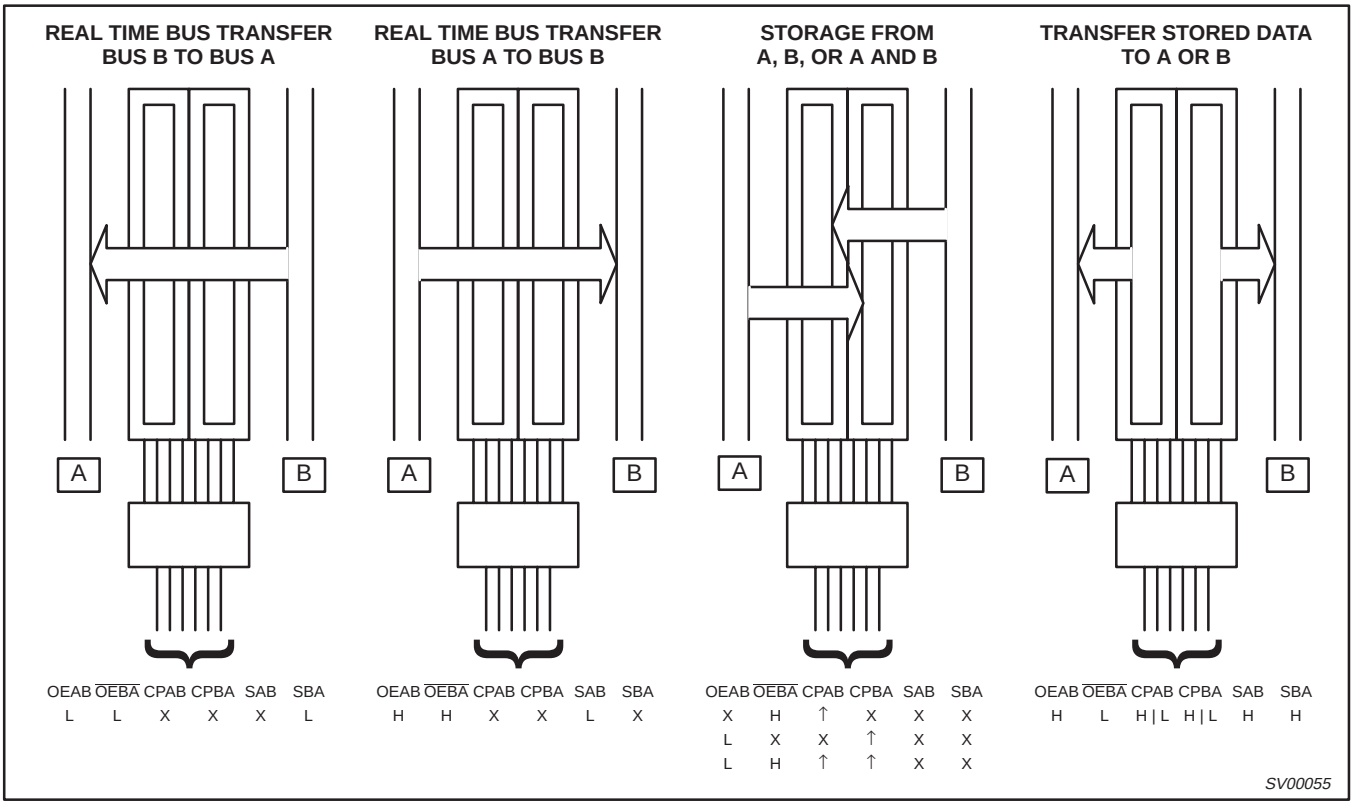
LOGIC DIAGRAM



The following examples demonstrate the four fundamental bus-management functions that can be performed with the 74LVT652.

The select pins determine whether data is stored or transferred through the device in real time.

The output enable pins determine the direction of the data flow.



FUNCTION TABLE

INPUTS						DATA I/O		OPERATING MODE
OEAB	$\overline{OEBA}$	CPAB	CPBA	SAB	SBA	An	Bn	
L L	H H	H or L ↑	H or L ↑	X X	X X	Input	Input	Isolation Store A and B data
X H	H H	↑ ↑	H or L ↑	X **	X X	Input	Unspecified** Output*	Store A, Hold B Store A in both registers
L L	X L	H or L ↑	↑ ↑	X X	X **	Unspecified** Output*	Input	Hold A, Store B Store B in both registers
L L	L L	X X	X H or L	X X	L H	Output	Input	Real time B data to A bus Stored B data to A bus
H H	H H	X H or L	X X	L H	X X	Input	Output	Real time A data to B bus Store A data to B bus
H	L	H or L	H or L	H	H	Output	Output	Stored A data to B bus Stored B data to A bus

H = High voltage level
L = Low voltage level
X = Don't care
↑ = Low-to-High clock transition
* The data output function may be enabled or disabled by various signals at the $\overline{OEBA}$ and OEAB inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every Low-to-High transition of the clock.
** If both Select controls (SAB and SBA) are Low, then clocks can occur simultaneously. If either Select control is High, the clocks must be staggered in order to load both registers.

ABSOLUTE MAXIMUM RATINGS[1,2]

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		–0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	–50	mA
V_I	DC input voltage[3]		–0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	–50	mA
V_{OUT}	DC output voltage[3]	Output in Off	–0.5 to +7.0	V
I_{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	–64	
T_{stg}	Storage temperature range		–65 to +150	°C

NOTES:
1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Input voltage		0.8	V
I_{OH}	High-level output current		–32	mA
I_{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V
T_{amb}	Operating free-air temperature range	–40	+85	°C

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP[1]	MAX	
V_{IK}	Input clamp voltage	V_{CC} = 2.7V; I_{IK} = –18mA			–0.9	–1.2	V
V_{OH}	High-level output voltage	V_{CC} = 2.7 to 3.6V; I_{OH} = –100µA		V_{CC}-0.2	V_{CC}-0.1		V
		V_{CC} = 2.7V; I_{OH} = –8mA		2.4	2.5		
		V_{CC} = 3.0V; I_{OH} = –32mA		2.0	2.2		
V_{OL}	Low-level output voltage	V_{CC} = 2.7V; I_{OL} = 100µA			0.1	0.2	V
		V_{CC} = 2.7V; I_{OL} = 24mA			0.3	0.5	
		V_{CC} = 3.0V; I_{OL} = 16mA			0.25	0.4	
		V_{CC} = 3.0V; I_{OL} = 32mA			0.3	0.5	
		V_{CC} = 3.0V; I_{OL} = 64mA			0.4	0.55	
V_{RST}	Power-up output low voltage[5]	V_{CC} = 3.6V; I_O = 1mA; V_I = GND or V_{CC}			0.13	0.55	V
I_I	Input leakage current	V_{CC} = 3.6V; V_I = V_{CC} or GND	Control pins		±0.1	±1	µA
		V_{CC} = 0 or 3.6V; V_I = 5.5V			1.0	10	
		V_{CC} = 3.6V; V_I = 5.5V	I/O Data pins[4]		1.0	20	
		V_{CC} = 3.6V; V_I = V_{CC}			0.1	1	
		V_{CC} = 3.6V; V_I = 0			–1	-5	
I_{OFF}	Output off current	V_{CC} = 0V; V_I or V_O = 0 to 4.5V			1	±100	µA
I_{HOLD}	Bus Hold current A inputs[6]	V_{CC} = 3V; V_I = 0.8V		75	150		µA
		V_{CC} = 3V; V_I = 2.0V		–75	–150		
		V_{CC} = 0V to 3.6V; V_{CC} = 3.6V		±500			
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	V_O = 5.5V; V_{CC} = 3.0V			60	125	µA
$I_{PU/PD}$	Power up/down 3-State output current[3]	$V_{CC} \leq$ 1.2V; V_O = 0.5V to V_{CC}; V_I = GND or V_{CC}; $\overline{OE}$/OE = Don't care			15	±100	µA
I_{CCH}	Quiescent supply current	V_{CC} = 3.6V; Outputs High, V_I = GND or V_{CC}, I_O = 0			0.13	0.19	mA
I_{CCL}		V_{CC} = 3.6V; Outputs Low, V_I = GND or V_{CC}, I_O = 0			3	12	
I_{CCZ}		V_{CC} = 3.6V; Outputs Disabled; V_I = GND or V_{CC}, I_O = 0			0.13	0.19	
ΔI_{CC}	Additional supply current per input pin[2]	V_{CC} = 3V to 3.6V; One input at V_{CC}-0.6V, Other inputs at V_{CC} or GND			0.1	0.2	mA

NOTES:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
4. Unused pins at V_{CC} or GND.
5. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.
6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V, $t_R = t_F$ = 2.5ns, C_L = 50pF, R_L = 500Ω; T_{amb} = –40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			V_{CC} = 3.3V ± 0.3V			V_{CC} = 2.7V	
			MIN	TYP[1]	MAX	MAX	
f_{MAX}	Maximum clock frequency	1	150	180			MHz
t_{PLH} t_{PHL}	Propagation delay CPAB to Bn or CPBA to An	1	1.8 2.0	3.7 3.7	6.0 5.7	6.9 6.4	ns
t_{PLH} t_{PHL}	Propagation delay An to Bn or Bn to An	2	1.2 1.0	2.8 2.6	4.7 4.6	5.5 5.3	ns
t_{PLH} t_{PHL}	Propagation delay SAB to Bn or SBA to An	3	1.4 1.4	3.7 4.0	6.4 6.2	7.6 6.8	ns
t_{PZH} t_{PZL}	Output enable time $\overline{OEBA}$ to An	5 6	1.0 1.0	2.9 3.0	5.8 6.0	7.2 7.3	ns
t_{PHZ} t_{PLZ}	Output disable time $\overline{OEBA}$ to An	5 6	2.2 1.8	3.9 3.2	6.5 5.8	6.9 5.9	ns
t_{PZH} t_{PZL}	Output enable time OEAB to Bn	5 6	1.0 1.2	3.3 3.4	6.5 6.3	7.5 7.1	ns
t_{PHZ} t_{PLZ}	Output disable time OEAB to Bn	5 6	1.7 1.5	4.5 3.8	7.2 5.8	8.1 6.3	ns

NOTE:
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC SETUP REQUIREMENTS

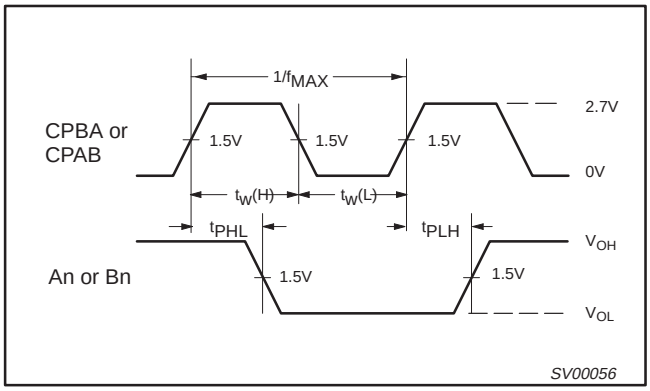
GND = 0V, t_R = 2.5ns, t_F = 2.5ns, C_L = 50pF, R_L = 500Ω, T_{amb} =40 °C to 85 °C

SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			T_{amb} = +25°C V_{CC} = +5.0V			T_{amb} = -40 to +85°C V_{CC} = +5.0V ±0.5V		
			Min	Typ	Max	Min	Max	
$t_s(H)$ $t_s(L)$	Setup time [1] An to CPAB, Bn to CPBA	4	1.5 2.2	0.9 1.1		1.6 2.5		ns
$t_h(H)$ $t_h(L)$	Hold time [1] An to CPAB, Bn to CPBA	4	0 0	–1.0 –1.0		0.0 0.0		ns
$t_w(H)$ $t_w(L)$	Pulse width, High or Low CPAB or CPBA	1	3.3 3.3	1.0 2.0		3.3 3.3		ns

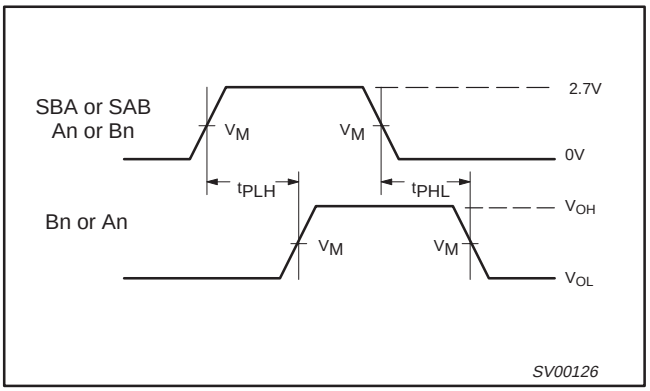
NOTE:
1. This data sheet limit may vary among suppliers.

AC WAVEFORMS

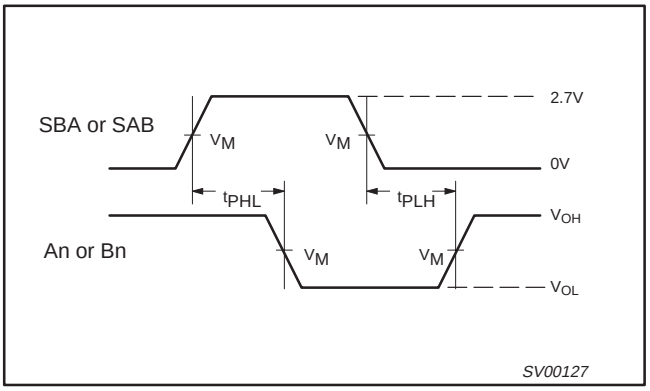
V_M = 1.5V, V_{IN} = GND to 2.7V



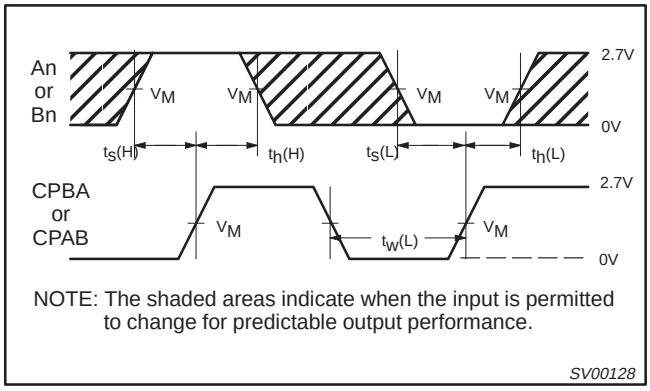
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



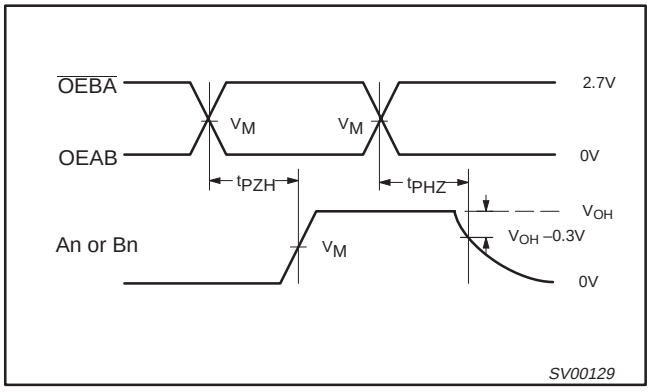
Waveform 2. Propagation Delay, An to Bn or Bn to An, SAB to Bn or SBA to An



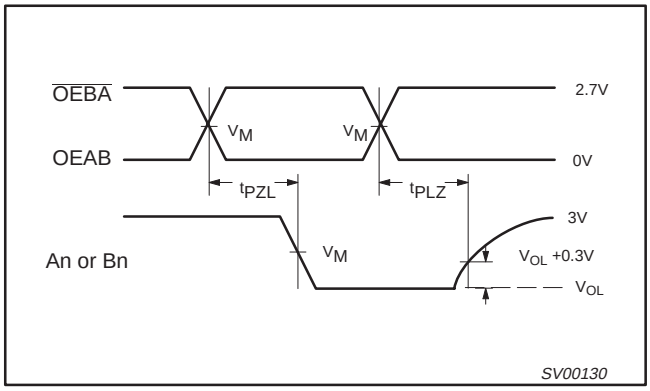
Waveform 3. Propagation Delay, SBA to An or SAB to Bn



Waveform 4. Data Setup and Hold Times

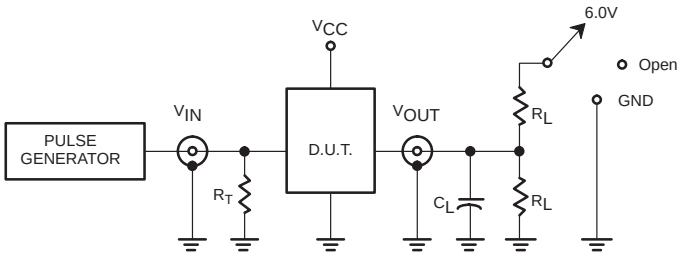


Waveform 5. 3-State Output Enable Time to High Level and Output Disable Time from High Level

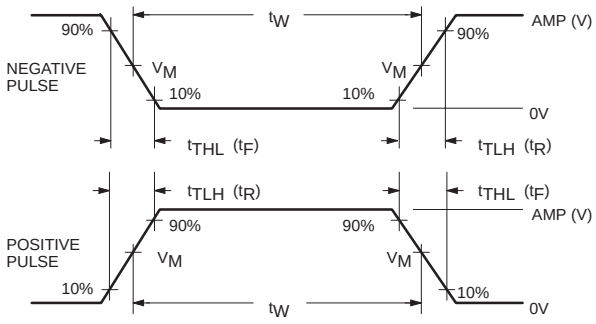


Waveform 6. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

TEST CIRCUIT AND WAVEFORM



Test Circuit for 3-State Outputs



V_M = 1.5V
Input Pulse Definition

SWITCH POSITION

TEST	SWITCH
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6V
t_{PHZ}/t_{PZH}	GND

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

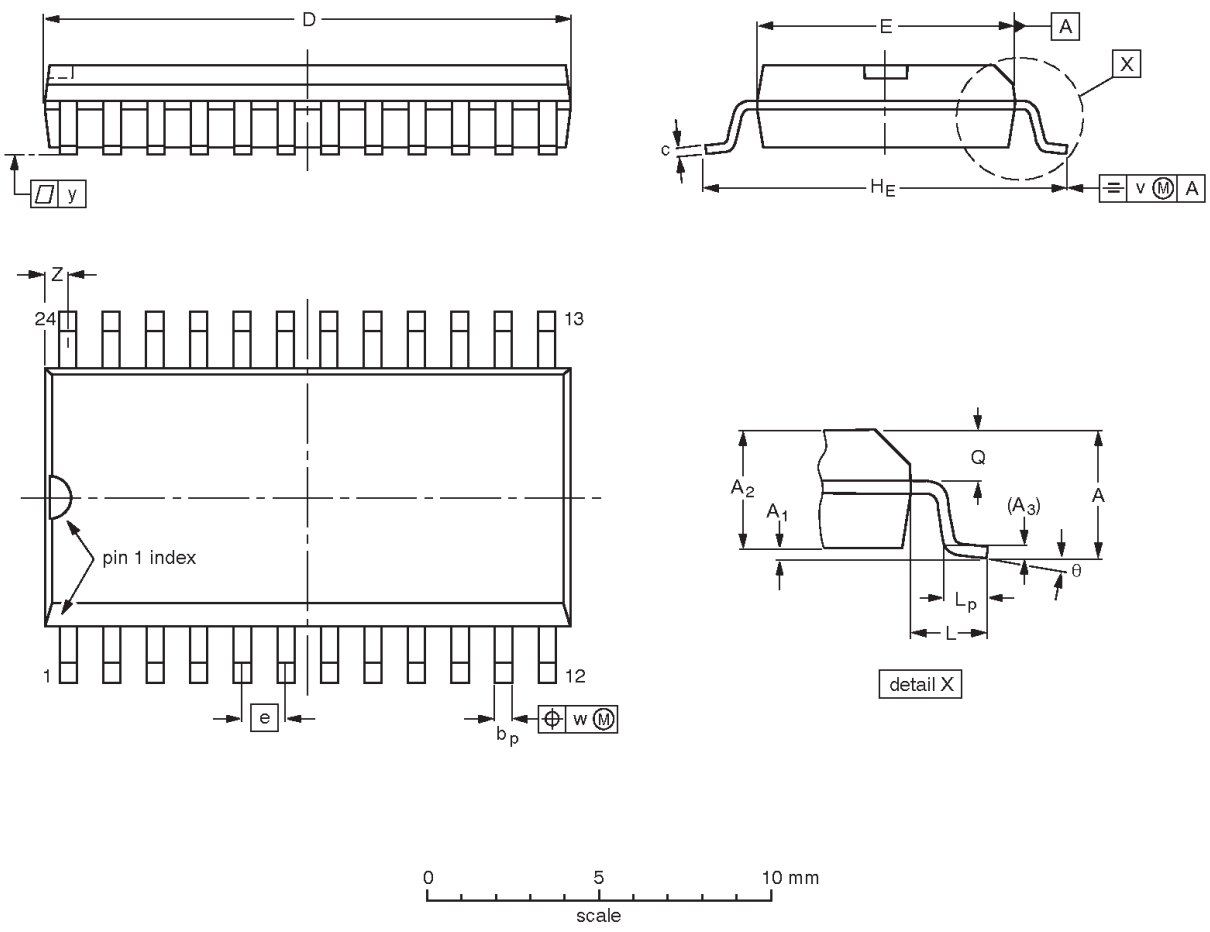
C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

SV00092

SO24: plastic small outline package; 24 leads; body width 7.5 mm **SOT137-1**



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

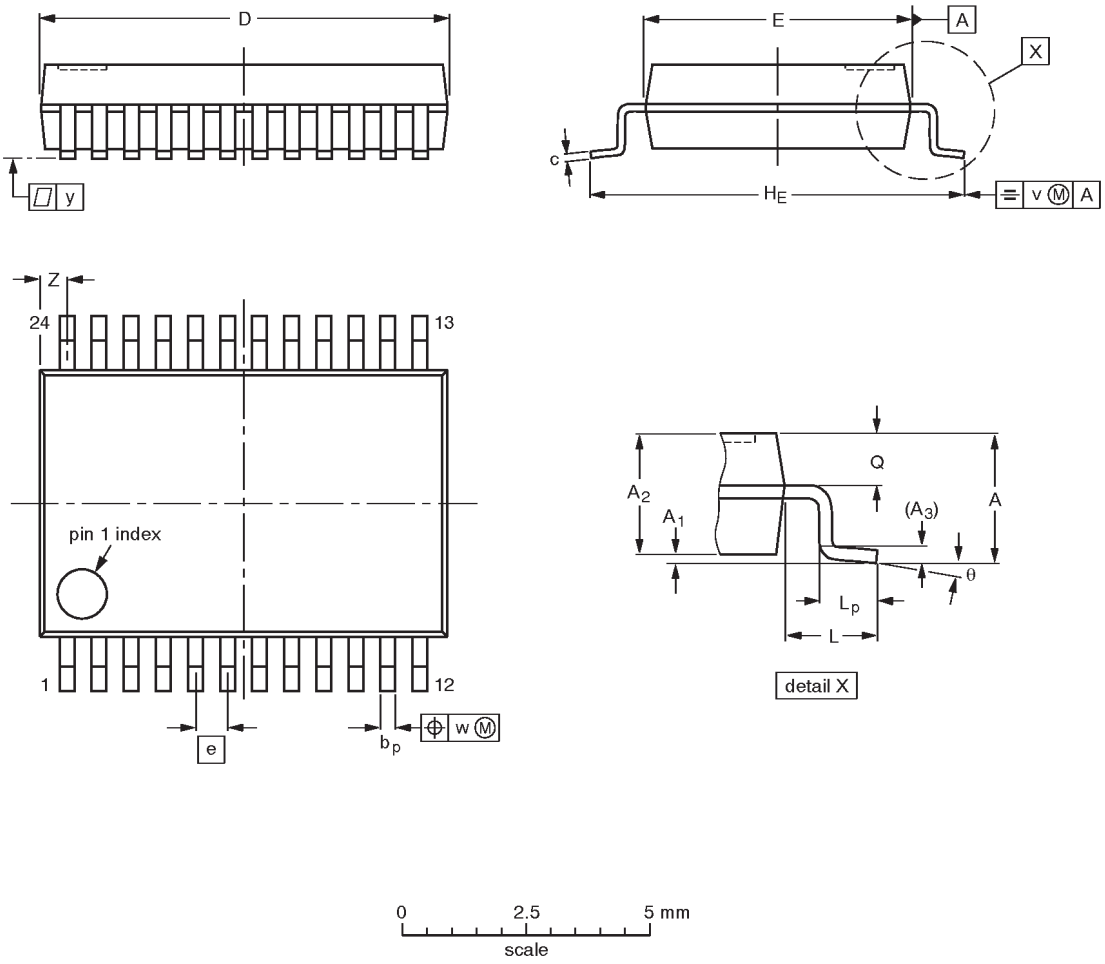
UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8^o 0^o
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT137-1	075E05	MS-013AD				~~95-01-24~~ 97-05-22

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm **SOT340-1**



DIMENSIONS (mm are the original dimensions)

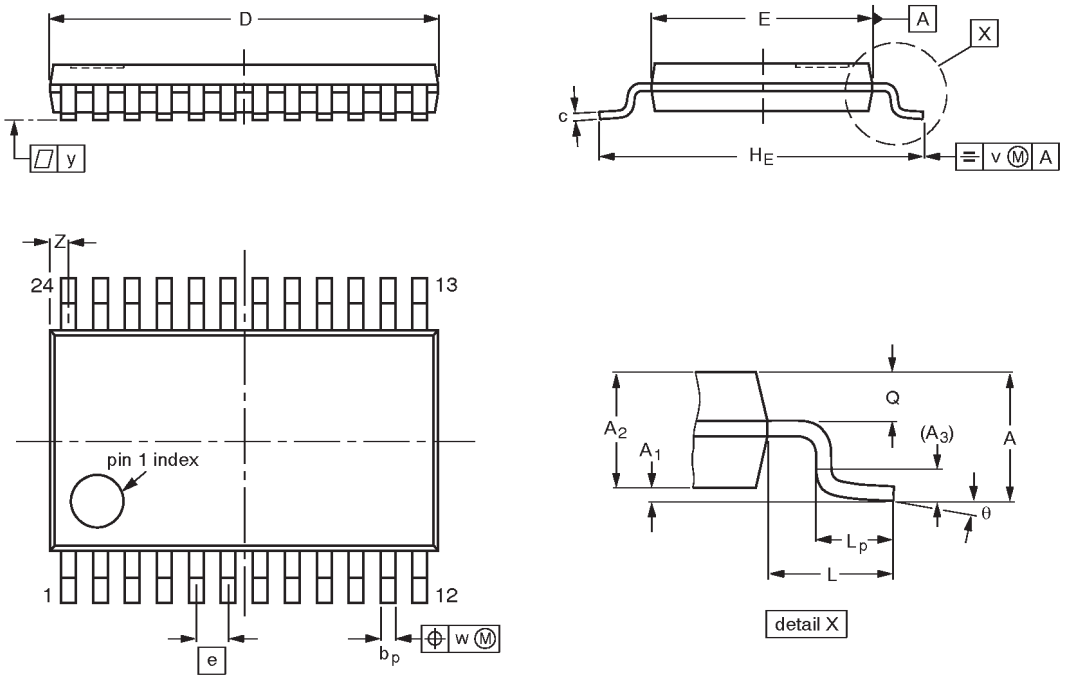
UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

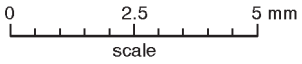
Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT340-1		MO-150AG				~~93-09-08~~ 95-02-04

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm SOT355-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(2)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT355-1		MO-153AD				~~93-06-16~~ 95-02-04

NOTES

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

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print code Date of release: 05-96

Document order number: 9397-750-03545

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